Supporting information

Improved electrochemical performance of CoS₂/MWCNT nanocomposites for sodium ion batteries

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EXPERIMENTAL SECTION

Preparation of CoS₂/**MWCNT nanocomposites**: CoS₂/MWCNT nanocomposites were synthesized by a simply hydrothermal method¹. 2.5 mmol cobalt dichloride (CoCl₂·6H₂O) and 2.5 mmol sodium thiosulfate (Na₂S₂O₃·5H₂O) was dissolved in 30mL deionized water under the magnetic stirring at room temperature. Then 40 mg MWCNT was added into the solution. The overall volume of the mixture suspension was adjusted to 80mL by adding deionized water. After ultra-sonication and string for 3h, the mixture suspension was transferred into a 100ml Teflon-lined autoclave, sealed tightly, and heated at 180°C for 12 h. After cooling naturally, the black precipitate was collected by centrifugation, washed with deionized water and ethanol several times, and dried at 80°C in a vacuum oven overnight. For comparison, the CoS₂ samples were also prepared by above similar process without the presence of MWCNT in the solution.

Characterization: The crystal structure of as-synthesized CoS_2 and $CoS_2/MWCNT$ samples were characterized by X-ray diffraction (XRD, BrukerD8 Advance, Germany) using Cu-K α radiation ($\lambda = 0.1540$ nm) at 1.6Kw, Data were processed using the MDI-Jade version 7.0 software. Raman spectra were achieved on a LABRAM-1Bconfocal Raman spectrometer with 647.1nm radiation from an Ar–Kr laser. Thermo-gravimetric (TG) analysis was carried out on a (Pyris 1TGA) thermal analyzer with a heating rate of 10°Cmin⁻¹in flowing air atmosphere. Transmission electron microscope (TEM) and selected area electron diffraction (SAED) measurements were carried out by 200KV side energy JEOL 2010 TEM with energy

dispersive X-ray (EDX) analyzers. For the *ex situ* measurements, to avoid the exposure to oxygen or water, care must be taken in the handling of samples at different states. The cell was disassembled in an Ar filled dry box and rinsed in anhydrous diglyme to eliminate residual salts then the active materials were rapidly transferred into the chambers.

For the electrochemical measurements, the working electrode consisted of active material (CoS₂ or CoS₂/MWCNT, 80 wt. %), electrical conductor (acetylene black, 10 wt. %), and binder (PVDF, 10 wt. %) on copper foil. The cells were assembled in an argon-filled glove box with the as-prepared materials as working electrode, and two sodium sheets as a counter and reference electrode, respectively. 1.0 M NaClO₄ (Aldrich) in a nonaqueous ethylene carbonate (EC)/propylene carbonate(PC) (1:1 in volume) and 1.0 M NaCF₃SO₃ (98%, Sigma-Aldrich) in diglyme ((CH₃OCH₂CH₂)₂O, anhydrous, 99.5%, Sigma-Aldrich) were selected as the electrolyte respectively. Galvanostatic charge-discharge cycles were carried out at room temperature with a Land CT 2001A battery test system. The cells were cycled between 1.0 and 2.9V vs. Na⁺/Na. Cyclic voltammogram (CV) tests were performed on a CHI660A electrochemical working station (CHI instruments, TN).



Figure S1 Thermogravimetric (TG) result of CoS₂/MWCNT and MWCNT in air with heating rate of 10°Cmin⁻¹.



Figure S2 Discharge/charge curves of (a) CoS_2 and (b) $CoS_2/MWCNT$ electrodes at a current density of 100 mA g⁻¹in 1 M NaClO₄-EC/PC.



Figure S3 Discharge/charge curves of MWCNT electrodes at a current density of 100 mA g⁻¹in (a) 1.0 M NaCF₃SO₃-DGM and (b) 1.0 M NaClO₄-EC/PC.



Figure S4 CV curves of (a) CoS_2 and (b) $CoS_2/MWCNT$ electrodes between 1.0 and 2.9 V (vs. Na/Na⁺) at the scan rate of 0.1 mV s⁻¹

Fig. S4 shows the cyclic voltammogram for CoS_2 and $CoS_2/MWCNT$ electrodes at scan rate of 0.1 mV s⁻¹ in the potential range of 1.0-2.9V. In the first cycle two reduction peaks at 1.1 and 1.4V and two oxidation peaks at 1.8 and 2.1 V are observed of both electrodes. The couple reduction/oxidation peaks may be related to multi-steps reaction mechanism. The reduction peak at 1.4V can be related to sodium insertion into CoS_2 forming Na_xCoS_2 and the peak at 1.1V can represents the conversion reaction forming Co and Na_2S .Whereas, in the subsequent cycles, these two couple of peaks for each cycle were almost overlapped, indicating that highly reversible reactions took place during the subsequent cycles.



Figure S5 High-resolution TEM (HRTEM) images of sodiated electrodes (a) $CoS_2/MWCNT$ and (b) CoS_2 .



Figure S6 TEM images and SAED patterns of (a, b) $CoS_2/MWCNT$ and (b) CoS_2 electrodes after charging to 2.9 V.



Figure S7 Co K-edge XANES spectra of pristine CoS_2 electrode (black line), after discharging to 1.0 V (red line) and charging to 2.9 V (blue line)

X-ray absorption spectroscopy was carried out to determine the variation in valence of Coin the sodiated and desodiated electrodes. Fig. S7 shows the Co K-edge XANES of the CoS_2 electrode after discharge to 1.0 V and recharge to 2.9 V, in comparing with the pristine sample. In the in initial state, the Fe K-edge absorption energy at 7714.7 eV could be assigned to Co^{2+} of CoS_2 . After discharging to 1.0 V, the Co K-edge shifted to the lower energy, indicating the formation of Co after discharging process. After charging to 2.9 V, the corresponding Co K-edge shifted to higher energy and fully recovered to the original state as the pristine CoS_2 .

Table S1 Sodium storage properties $ofCoS_2$ and other transition metal sulfides, oxides and selenides reported recently.

		Discharge	Second	Electrochemical		
Materials	Curve	plateau	discharge	Performance	Reaction	Reference
	shape	voltage(V)	capacity	(mAh g ⁻¹)	mechanism	
-			(mAh g ⁻¹)			
TiS ₂	Platform	2.2	210	$150(40^{\text{th}})$ at 0.04A g ⁻¹	insertion	4
SnS	Platform	1.2	500	$370(30^{\text{th}})$ at 0.125A g ⁻¹	conversion	5
Cu ₂ S	Platform	1.0	260	$261(20^{\text{th}})$ at 0.05A g ⁻¹	insertion	6
Ni3S ₂	Platform	0.9	370	250(40th) at 1C	conversion	7
MoS ₂ -C	Platform	1.0	500	390(100 th) at 0.1A g ⁻¹	conversion	8
WS ₂	Slope	1.0	297	32 (500 th) at 0.02A g ⁻¹	conversion	9
WS ₂ /G	Slope	1.2	584	329(500 th) at 0.02A g ⁻¹	conversion	9
FeS ₂	Slope	1.5-2.0	530	415(100 th) at 0.06mAg ⁻¹	conversion	11
FeS ₂	Slope	1.5-2.0	250	170(2000 th) at 1A g ⁻¹	insertion	12
MoS ₂ /G	Slope	1.5	380	300(200 th) at 0.1 A g ⁻¹	conversion	S2
VS ₂	Platform	1.8	70mAh	60mAh(22 th)at0.5mAcm ⁻²	insertion	S3
$Nb_{1.1}S_2$	Platform	1.5	40mAh	26mAh(17th)at0.5mAcm ⁻²	insertion	S3
SeS ₂	Slope	0.5-3.5	500	288(30 th) at 0.1A g ⁻¹	conversion	S4
CoS ₂	Platform	1.4	724	194(100 th) at 0.1A g ⁻¹	conversion	T.W
CoS ₂ /CNT	platform	1.4	735	568(100 th) at 0.1A g ⁻¹	conversion	T.W
V_2O_5	Slope	2.5-3.5	180	170(20th) at 0.04A g ⁻¹	insertion	S5
VO ₂	Slope	2-3.7	200	150(50th) at 0.05A g ⁻¹	insertion	S6
V ₆ O ₁₃	Slope	2-3.0	170	120(30th) at 0.04A g ⁻¹	insertion	S7
Fe ₃ O ₄	Slope	1.8	140	90(35th) at 0.02A g ⁻¹	insertion	S8
Alpha-MoO ₃	Slope	1.4	210	116(500 th) at 0.2C	conversion	S9
Fe ₂ O ₃	Platform	1.0	580	385(200 th) at 0.1A g ⁻¹	conversion	S10
NiO	Platform	0.7	550	220(100 th) at 0.1A g ⁻¹	conversion	S10
C0 ₃ O ₄	Platform	0.75	450	180(100 th) at 0.1A g ⁻¹	conversion	S10
Mn ₃ O ₄	Slope	1.3	157	120(100 th) at 0.1A g ⁻¹	conversion	S10
Sb ₄ O ₂	Platform	0.9	900	724(20 th) at 0.7C	conversion	S11
CuO bulk	Platform	0.75	280	53(50 th) at 0.05A g ⁻¹	conversion	S12
CuO	Platform	0.75	480	303(50 th) at 0.05A g ⁻¹	conversion	S12
nanowires						
TiO ₂	Slope	2.0	90	150 (15 th) at 0.05A g ⁻¹	insertion	S13
SnO ₂ /G	Slope	0.7-1.5	225	175(100 th) at 0.02A g ⁻¹	conversion	S14
SnO ₂ /NG	Slope	0.7-1.5	300	$250(200^{\text{th}})$ at 0.08A g ⁻¹	conversion	S14
Cu ₂ Se	Platform	1.9	200	114(100 th) at 0.025 A g ⁻¹	conversion	S15
VSe ₂	Platform	1.6	48mAh	46mAh(24th)at1 µ Acm ⁻²	insertion	S16
TiSe ₂	Slope	1.5	70mAh	65mAh(6 th)at1 µ Acm ⁻²	insertion	S16
MoSe ₂	Slope	0.7/2.1	108	65(8 th) at0.25mAcm ⁻²	insertion	S17
*T.W=This Work; G:graphene; NG: nitrogen doped graphene; CNT: carbon nanotube						

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